



3 GHz SMA N/O S.P.12T. SWITCH

OPTIONS : / TTL DRIVE /SUPP.DIODES

**R F CHARACTERISTICS**

NUMBER OF WAYS : 12  
 FREQUENCY RANGE : 0 - 3 GHz  
 IMPEDANCE : 50 Ohms

FREQUENCY (GHz)	0 - 3
V.S.W.R <=	1.20
INSERT. LOSS <=	0.20 dB
ISOLATION >=	80 dB
AVER. POWER (*)	120 W

**ELECTRICAL CHARACTERISTICS**

ACTUATOR : NORMALLY OPEN  
 NOMINAL CURRENT AT 25° C (±10%) : 250 mA  
 ACTUATOR VOLTAGE (Vcc) : 12V (10.2 to 13V) / NEGATIVE COMMON  
 TERMINALS : solder pins (250 deg.C max./30 sec.)  
 TTL INPUTS (E) - High level : 2.2 to 5.5V / 800µA at 5V  
                                   - Low level : 0 to 0.8V / 20µA at 0.8V

**MECHANICAL CHARACTERISTICS**

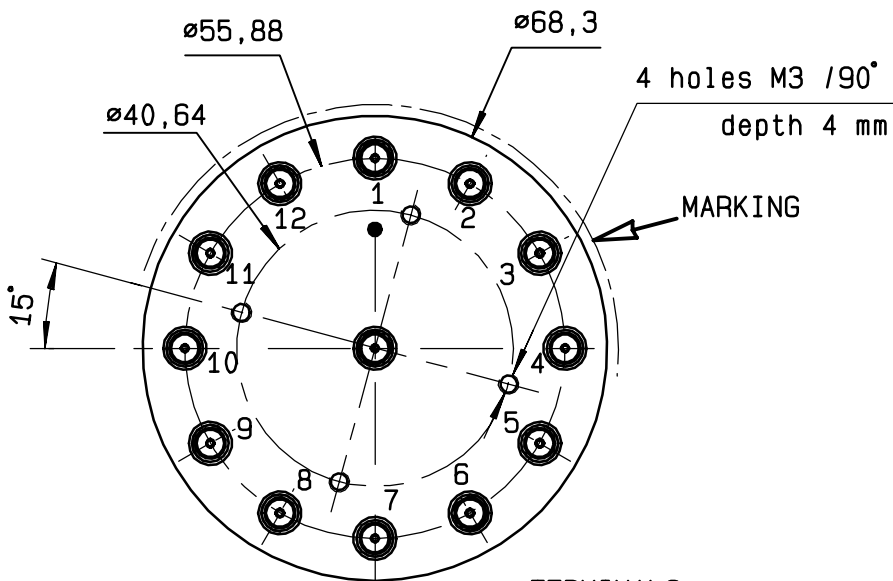
CONNECTORS : SMA female per MIL-C 39012  
 LIFE : 2.000.000 cycles per position  
 SWITCHING TIME (nominal voltage;25° C) : < 15 ms  
 CONSTRUCTION : splashproof  
 WEIGHT : < 400 g

**ENVIRONMENTAL CHARACTERISTICS**

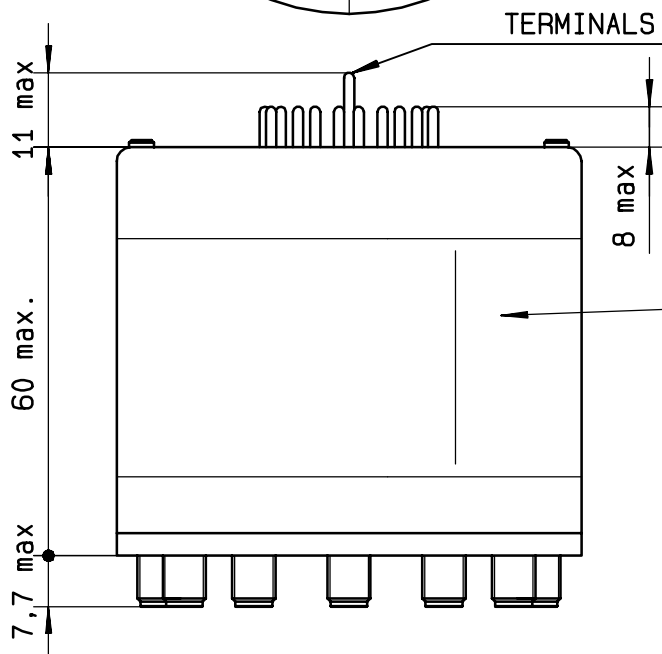
OPERATING TEMPERATURE RANGE (°C) : -40 , +85  
 STORAGE TEMPERATURE RANGE (°C) : -55 , +85

(\* : average power at 25° C per RF path)

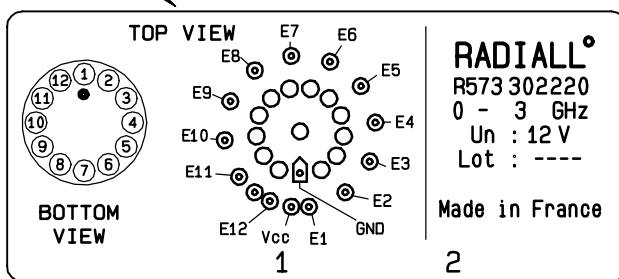
This information is given as an indication. In the continual goal to improve our products, we reserve the right to make any modifications judged necessary



TTL input	RF continuity
E1 = 1	IN ↔ 1
E2 = 1	IN ↔ 2
E3 = 1	IN ↔ 3
E4 = 1	IN ↔ 4
E5 = 1	IN ↔ 5
E6 = 1	IN ↔ 6
E7 = 1	IN ↔ 7
E8 = 1	IN ↔ 8
E9 = 1	IN ↔ 9
E10 = 1	IN ↔ 10
E11 = 1	IN ↔ 11
E12 = 1	IN ↔ 12

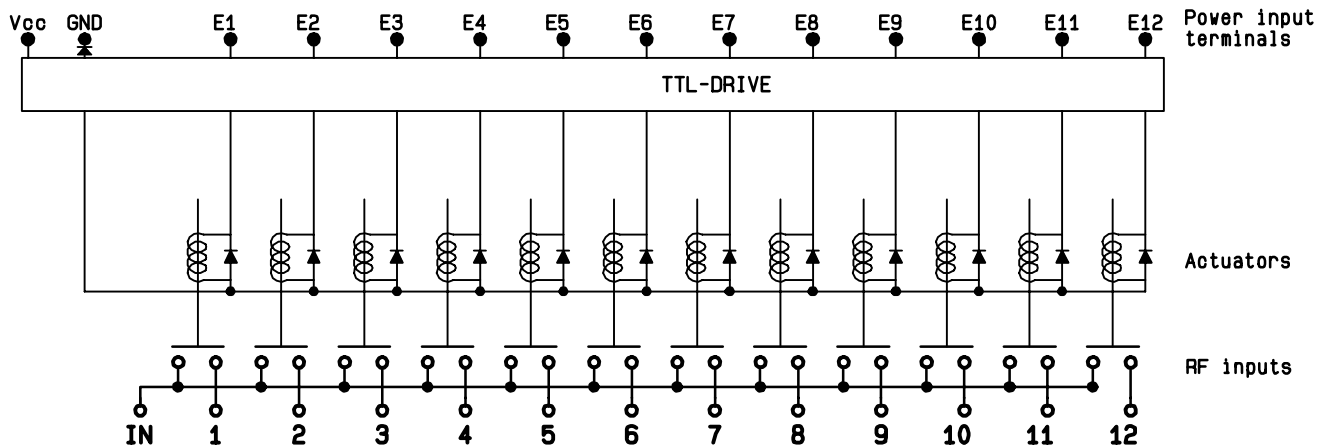


MARKING TOP VIEW (TERMINALS)



**RADIALL<sup>o</sup>**  
 R573 302220  
 0 - 3 GHz  
 Un : 12 V  
 Lot : ----  
 Made in France  
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**SCHEMATIC DIAGRAM**



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